Unit: mm

TOSHIBA PHOTOCOUPLER IRED + PHOTO-IC

TLP719

Digital logic ground isolation Line receivers Microprocessor system interfaces Switching power supply feedback control Industrial invertors

The TOSHIBA TLP719 consists of a high-output infrared emitting diode and a highspeed detector.

This unit is a 6-lead SDIP. The TLP719 is 50% smaller than the 8-pin DIP and meets the reinforced insulation class requirements of international safety standards. Therefore the mounting area can be reduced in equipment requiring safety standard certification.

The TLP719 has a Faraday shield integrated on the photodetector chip to provide an effective common mode noise transient immunity. Therefore this product is suitable for application in noisy environmental conditions.

Open collector

Package type : SDIP6

: 5000 Vrms (min) Isolation voltage

Common mode transient immunity : $\pm 10 \text{ kV/}\mu\text{s}$ (min) @V_{CM} = $400 \text{ V}_{p^{-}p}$

Switching speed : $t_{\text{pHL}}/t_{\text{pLH}} = 0.8 \, \mu \text{s} \, (\text{max})$

@ $I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V},$

 $R_L = 1.9 \text{ k}\Omega$, Ta = 25 °CTTL compatible

Construction mechanical rating

	7.62-mm pitch standard type	10.16-mm pitch TLPXXXF type
Creepage Distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation Thickness	0.4 mm (min)	0.4 mm (min)

UL-recognized : UL 1577, File No.E67349

cUL-recognized : CSA Component Acceptance Service No.5A

File No.E67349

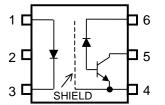
: EN 60747-5-5, EN 62368-1 (Note1) VDE-approved

Note 1: When a VDE approved type is needed,

please designate the Option(D4).

4.58±0.25 7.62±0.25 1.25±0.25 9.7±0.3 TOSHIBA 11-5J1S Weight: 0.26 g (typ.)

PIN CONFIGURATION (Top View)



1: ANODE 2: N.C.

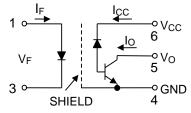
3: CATHODE

4: EMITTER (GND)

5: COLLECTOR (OUTPUT)

6 : Vcc

SCHEMATIC



A 0.1-μF bypass capacitor must be connected between pins 4 and 6.

Start of commercial production 2007-09

Absolute Maximum Ratings (Ta = 25 °C)

	Characteristic	Symbol	Rating	Unit
	Forward current	lF	25	mA
	Forward current derating (Ta ≥ 70 °C)	IF/ Ta	-0.45	mA / °C
	Pulse forward current (Note 1)	lfp	50	mA
LED	Peak transient forward current (Note 2)	IFPT	(1)	А
	Reverse voltage	VR	(5)	V
	Diode power dissipation (Note 3)	PD	45	mW
	Junction temperature	ĬĮ (125	°C
	Output current	10	8	mA
	Peak output current	lop	16	mA
ō	Output voltage	VO	-0.5 to 20	V
Detector	Supply voltage	Vcc	-0.5 to 30	A
ă	Output power dissipation	Po	100	mW
	Output power dissipation derating (Ta ≥ 70 °C)	Po / Ta	-1.8	mW/°C
	Junction Temperature	Tj	125	⊘ °C
Оре	Operating temperature range		-55 to 100	°C
Stor	Storage temperature range		-55 to 125	°C
Lea	Lead soldering temperature (10 s)		260	°C
Isola	ation voltage (AC, 60 s, R.H.≤ 60 %) (Note 4)	BVs	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: A ceramic capacitor (0.1 μF) should be connected from pin 6 to pin 4 to stabilize the operation of the highgain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.

Note 1: 50 % duty cycle, 1 ms pulse width. Derate 0.9 mA / °C above 70 °C.

Note 2: Pulse width ≤ 1 µs, 300 pps.

Note 3: Derate 0.8 mW / °C above 70 °C.

Note 4: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.

Electrical Characteristics (Ta = 25 °C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 16 mA	_	1.65	1.85	V
LED	Forward voltage Temperature coefficient	ΔV _F / ΔTa	IF = 16 mA	_	-2		mV / °C
=	Reverse current	I_R	V _R = 5 V	/_	_	10	μΑ
	Capacitance between terminals	Ст	VF = 0 V, f = 1 MHz		45	_	pF
Detector	HIGH-level output current	IOH (1)	IF = 0 mA, VCC = VO = 5.5 V		3	500	nA
		IOH (2)	$I_F = 0 \text{ mA}, V_{CC} = 30 \text{ V}$ $V_O = 20 \text{ V}$	}	_	5	
		Іон	I _F = 0 mA, V _{CC} = 30 V V _O = 20 V, Ta = 70 °C	_	_	50	μΑ
	HIGH-level supply current	Іссн	IF = 0 mA, VCC = 30 V	_	0.01	1	μΑ
	Supply voltage	Vcc	ICC = 0.01 mA	30	ZF)	<u> </u>	V
	Output voltage	Vo	Io = 0.5 mA	20 🕎		> 1	V

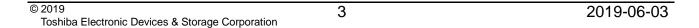
Coupled Electrical Characteristics (Ta = 25 °C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	lo/l _F	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$ $V_O = 0.4 \text{ V}$	20	_	1	%
LOW-level output voltage	I VOI	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$ $I_O = 2.4 \text{ mA}$	_	_	0.4	V

Isolation Characteristics (Ta = 25°C)

		2 11 3				
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	R.H. ≤ 60 %,V _S = 500 V	1×10 ¹²	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	5000	_	_	V _{rms}

Note: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.



Switching Characteristics (Ta = 25 °C, Vcc = 5 V)

Characteristic	Symbol	Test Cir- cuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time $(H \rightarrow L)$	t _{pHL}	Fig.1	$I_F = 0 \rightarrow 16 \text{ mA}$ $R_L = 1.9 \text{ k}\Omega$	_	_	0.8	μS
Propagation delay time (L→ H)	t _{pLH}	Fig1	$I_F = 16 \rightarrow 0 \text{ mA}$ $R_L = 1.9 \text{ k}\Omega$		_	0.8	μS
Common mode transient immunity at logic HIGH output (Note 1)	СМн	Fig2	$I_F = 0 \text{ mA}$ $V_{CM} = 400 \text{ Vp-p}$ $R_L = 1.9 \text{ k}\Omega$	10000)}-	_	V / μs
Common mode transient immunity at logic LOW output (Note 1)	CML		$I_F = 16 \text{ mA}$ $V_{CM} = 400 \text{ Vp-p}$ $R_L = 1.9 \text{ k}\Omega$	-10000	_	_	V / μs

Note 1 : CM_L is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic LOW state ($V_O < 0.8 \text{ V}$).

 CM_H is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic HIGH state ($V_O > 2.0 \text{ V}$).

Figure 1. Switching Time Test Circuit

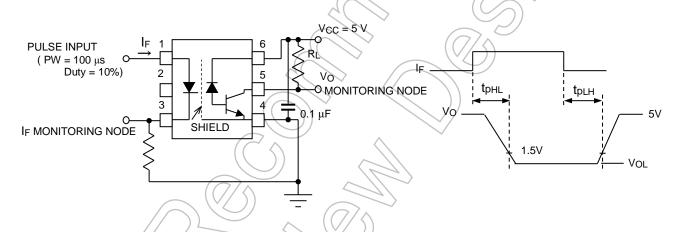
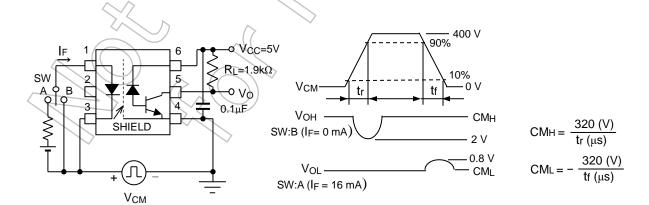
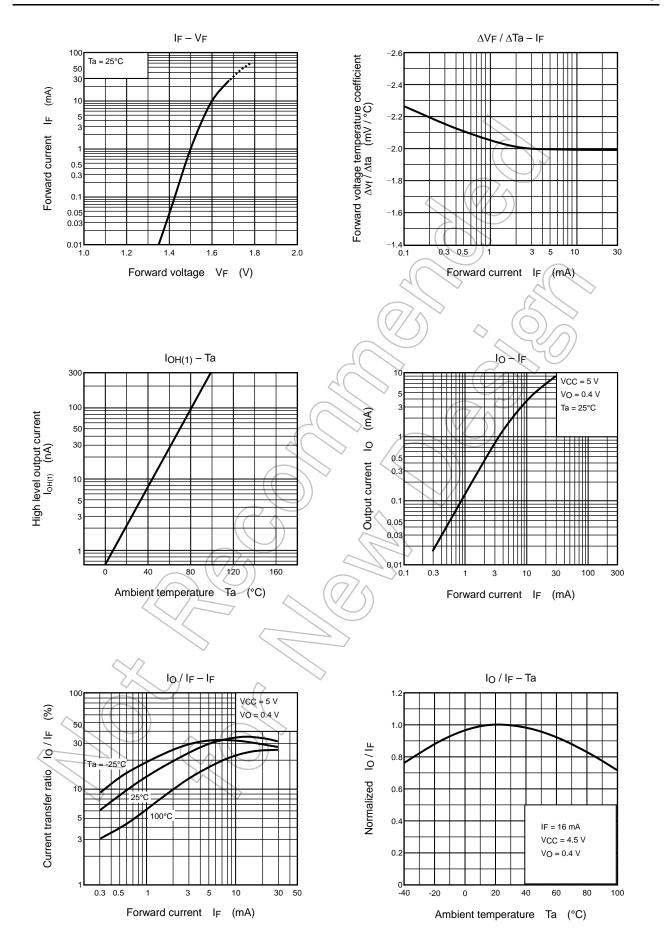
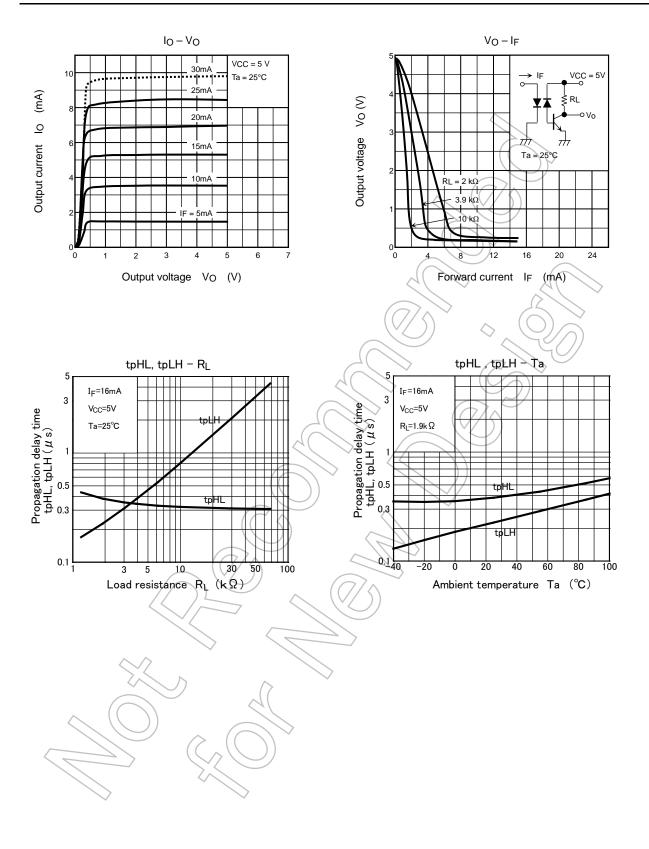


Figure 2. Common Mode Noise Immunity Test Circuit.





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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